## UNLEASHING UNPRECEDENTED PERFORMANCE



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# SILICON CARBIDE

Silicon carbide is:

1.5% 10 THAN LEGACY SILICON COUNTERPARTS Silicon carbide enables cutting-edge power electronics: **10 x HIGHER SWITCHING FREOUENCIES POWER LOSSES 50**% **BY AS MUCH AS** 98% **ACHIEVING: HIGHER POWER CONVERSION EFFICIENCIES** 

The revolutionary semiconductor material is propelling us into a future of immense possibilities - a future where energy efficiency, sustainability, and technological advancements converge. With its transformative impact on

various industries, silicon carbide is set to shape the world of tomorrow,

making it smarter, more efficient and more connected than ever before.

MORE ENERGY EFFICIENT

Silicon Carbide has the possibility of operating in temperatures over...

> Silicon carbide-powered data centers can save enough energy to power Manhattan for a year, offsetting...

**150°**C

**1 1 2** 

... of global energy consumption projected for data centers by 2050.







Plays a crucial role in **optimizing** energy conversion and storage in renewable energy systems.



Revolutionizes industrial applications, enabling high-temperature operation and robust components.

Silicon carbide technology:



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Drives smaller, lighter, and more efficient power devices.

Contributes to the acceleration of

the EV market, enabling faster

charging and longer ranges.

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## ACCELERATING ELECTROMOBILITY

Silicon carbide's game-changing properties are driving the rapid growth of electric vehicles (EVs), enabling faster charging times, extended driving ranges, and lower overall costs.

In electric vehicles, silicon carbide provides:

#### From Race to Road

TNIN

CONSULTANCY SERVICES

Our silicon carbide semiconductor technology in the Jaguar I-TYPE 6<sup>1</sup> creates an 'Innovation Lab on Wheels' to engineer improved powertrain efficiency in a high-performance electric vehicle.

<sup>1</sup>Wolfspeed is the Official Power Semiconductor Partner to Jaguar TCS Racing on the Formula E Circuit

UNLEASHING UNPRECEDENTED PERFORMANCE





**10**%

**50**%

LOWER LOSSES

**80**%

**REDUCTION IN POWER LOSSES** 

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# POWERING RENEWABLE ENERGY

Silicon carbide semiconductors enhance the efficiency of renewable energy systems, such as solar and wind power, maximizing energy conversion and reducing losses.

### Solar inverters using silicon carbide can achieve over:

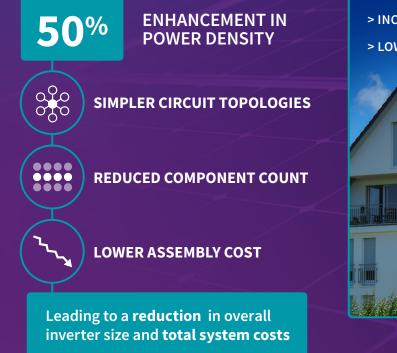


EFFICIENCY

Enabling far more effective utilization of solar energy



IMPROVEMENT In power conversion efficiencies Replacing traditional silicon with silicon carbide in three-phase inverters can create a:



Silicon carbide MOSFETs in residential solar inverters create:

> INCREASED POWER DENSITY

> LOWER SWITCHING LOSSES

In a 7kW residential inverter, silicon carbide can provide impressive and significant improvements compared with silicon MOSFETS:



HIGHER EFFICIENCES

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**48**<sup>kHz</sup>

SIGNIFICANT INCREASE IN POWER DENSITY (3kW/L vs. 2.5 kW/L)

#### SWITCHING FREQUENCY

(a full 32 kHz higher than using silicon MOSFETs)

🖽 Powering Renewable Energy

### ENABLING NEXT-GEN INDUSTRIES AND DATA CONNECTIVITY

Silicon carbide is the cornerstone of our future, unlocking unparalleled possibilities in technology and sustainability. It supports the ever-growing demand for data connectivity by empowering more efficient, high-speed communication networks, data centers, and IoT devices.

#### Silicon carbide enables:

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FASTER PROCESSING

**INCREASED BANDWIDTH CAPACITY** 

ENHANCED EFFICIENCY

2% of all electrical energy in the U.S. is consumed by data centers

From 2010 to 2020, servers running silicon carbide devices will have contributed

### 620 billion kWh

in energy savings.



Enabling Next-Gen Industries and Data Connectivity

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### Compared with traditional silicon devices, power devices using silicon carbide can:

Enable faster data processing with up to:

**10x** 

FASTER SWITCHING SPEEDS

Improve thermal performance to create up to:

**40**%

SAVINGS IN ENERGY COSTS FOR DATA CENTER COOLING

Achieve switching speeds in the nanosecond range:

**10**<sup>-9</sup>